Technical Data Data Sheet 4959, Rev. A.1

# SILICON SCHOTTKY RECTIFIER DIE Low Forward Voltage Drop

## **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

#### Features:

- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

**Maximum Ratings**(1):

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	100	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle, rectangular	1	Α
Current		wave form		
Max. Peak One Cycle Non-	I <sub>FSM</sub>	8.3 ms, half Sine wave (1)	20	Α
Repetitive Surge Current				
Non-Repetitive Avalanche	Eas	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 0.74  A,$	5.0	mJ
Energy		L = 12 mH		
Repetitive Avalanche Current	I <sub>AR</sub>	I <sub>AS</sub> decay linearly to 0 in 1 μs	0.74	Α
		f limited by T <sub>J</sub> max V <sub>A</sub> =1.5V <sub>R</sub>		
Max. Junction Temperature	TJ	-	-55 to +175	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C

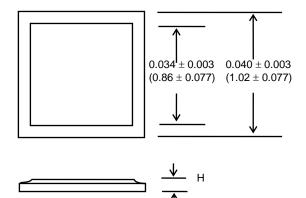
## **Electrical Characteristics**(1):

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 1A, Pulse, T <sub>J</sub> = 25 °C	0.84	V
	V <sub>F2</sub>	@ 1A, Pulse, T <sub>J</sub> = 125 °C	0.70	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 100V, Pulse,	0.03	mA
		T <sub>J</sub> = 25 °C		
	I <sub>R2</sub>	@V <sub>R</sub> = 100V, Pulse,	0.6	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	35	pF
		fsig = 1MHz,		
		$V_{SIG} = 50 \text{mV (p-p)}$		

(1) in SHD package

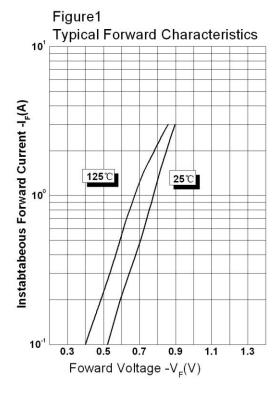
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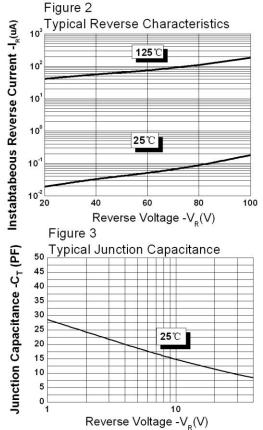
#### Mechanical Dimensions: In Inches / mm



Bottom side metallization Ag thickness is 5kA Bottom side metallization Ag- 30kA Min or Ag- 30kA min Top side metallization Al thickness is 25kA

Bottom side is cathode, top side is anode Dimension H =0.0105 $\pm$ .001 (0.27 $\pm$ .026) for Al top Dimension H =0.0155 $\pm$ .001 (0.39 $\pm$ .026) for Ag top







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#### PART ORDERING INFORMATION:



### Metallization:

Suffix	Part Number	Description
Α	SD040SB100A	Al top, Ag bottom
В	SD040SB100B	Ag top, Ag bottom

#### Quality Level:

Suffix	Part Number	Description
Н	SD040SB100AH	Class H Element Eval
K	SD040SB100AK	Class K Element Eval

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